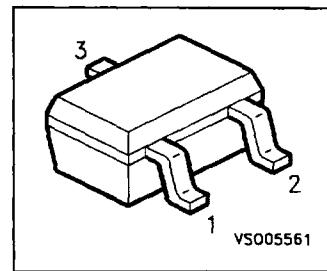
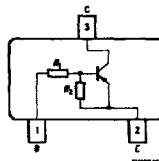


**PNP Silicon Digital Transistor**

- Switching circuit, inverter, interface circuit, driver circuit
- Built in bias resistor ( $R_1=4.7\text{k}\Omega$ ,  $R_2=47\text{k}\Omega$ )



| Type     | Marking | Ordering Code | Pin Configuration |     |     | Package |
|----------|---------|---------------|-------------------|-----|-----|---------|
| BCR 166W | WTs     | UPON INQUIRY  | 1=B               | 2=E | 3=C | SOT-323 |

**Maximum Ratings**

| Parameter  | Symbol      | Values         | Unit             |
|--|-------------|----------------|------------------|
| Collector-emitter voltage                          | $V_{CEO}$   | 50             | V                |
| Collector-base voltage                             | $V_{CBO}$   | 50             |                  |
| Emitter-base voltage                               | $V_{EBO}$   | 5              |                  |
| Input on Voltage                                   | $V_{i(on)}$ | 15             |                  |
| DC collector current                               | $I_C$       | 100            |                  |
| Total power dissipation, $T_S = 124^\circ\text{C}$ | $P_{tot}$   | 250            |                  |
| Junction temperature                               | $T_J$       | 150            |                  |
| Storage temperature                                | $T_{stg}$   | - 65 ... + 150 | $^\circ\text{C}$ |

**Thermal Resistance**

|                                |            |            |     |
|--------------------------------|------------|------------|-----|
| Junction ambient <sup>1)</sup> | $R_{thJA}$ | $\leq 240$ | K/W |
| Junction - soldering point     | $R_{thJS}$ | $\leq 105$ |     |

1) Package mounted on pcb 40mm x 40mm x 1.5mm / 0.5cm<sup>2</sup> Cu

**Electrical Characteristics** at  $T_A=25^\circ\text{C}$ , unless otherwise specified

| Parameter | Symbol | Values |      |      | Unit |
|-----------|--------|--------|------|------|------|
|           |        | min.   | typ. | max. |      |

#### DC Characteristics

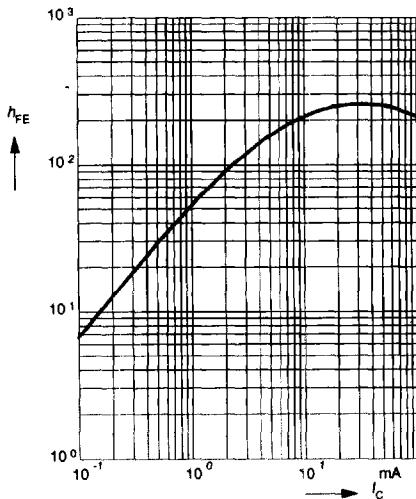
|  |                             |      |     |      |    |
|--|-----------------------------|------|-----|------|----|
| Collector-emitter breakdown voltage<br>$I_C = 100 \mu\text{A}, I_B = 0$                | $V_{(\text{BR})\text{CEO}}$ | 50   | -   | -    | V  |
| Collector-base breakdown voltage<br>$I_C = 10 \mu\text{A}, I_B = 0$                    | $V_{(\text{BR})\text{CBO}}$ | 50   | -   | -    |    |
| Collector cutoff current<br>$V_{CB} = 40 \text{ V}, I_E = 0$                           | $I_{\text{CBO}}$            | -    | -   | 100  | nA |
| Emitter cutoff current<br>$V_{EB} = 5 \text{ V}, I_C = 0$                              | $I_{\text{EBO}}$            | -    | -   | 155  | μA |
| DC current gain<br>$I_C = 5 \text{ mA}, V_{CE} = 5 \text{ V}$                          | $h_{\text{FE}}$             | 70   | -   | -    | -  |
| Collector-emitter saturation voltage 1)<br>$I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$ | $V_{\text{CESat}}$          | -    | -   | 0.3  | V  |
| Input off voltage<br>$I_C = 100 \mu\text{A}, V_{CE} = 5 \text{ V}$                     | $V_{i(\text{off})}$         | 0.4  | -   | 0.8  |    |
| Input on Voltage<br>$I_C = 2 \text{ mA}, V_{CE} = 0.3 \text{ V}$                       | $V_{i(\text{on})}$          | 0.5  | -   | 1.4  |    |
| Input resistor   | $R_1$                       | 3.2  | 4.7 | 6.2  | kΩ |
| Resistor ratio   | $R_1/R_2$                   | 0.09 | 0.1 | 0.11 | -  |

#### AC Characteristics

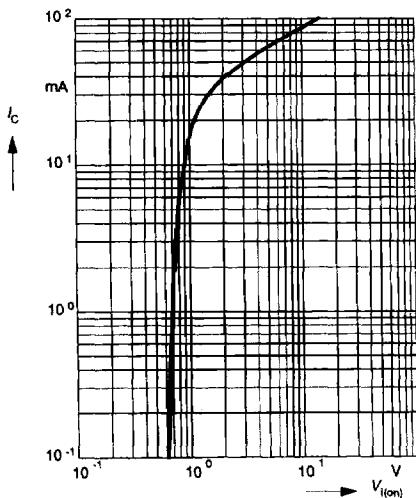
|  |          |   |     |   |     |
|--|----------|---|-----|---|-----|
| Transition frequency<br>$I_C = 10 \text{ mA}, V_{CE} = 5 \text{ V}, f = 100 \text{ MHz}$ | $f_T$    | - | 160 | - | MHz |
| Collector-base capacitance<br>$V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}$                 | $C_{cb}$ | - | 3   | - | pF  |

1) Pulse test:  $t < 300 \mu\text{s}; D < 2\%$

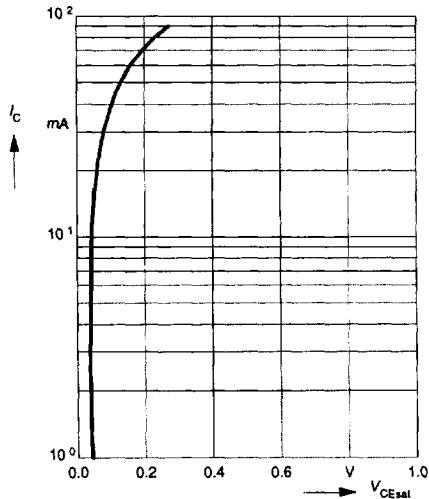
**DC Current Gain**  $h_{FE} = f(I_C)$   
 $V_{CE} = 5V$  (common emitter configuration)



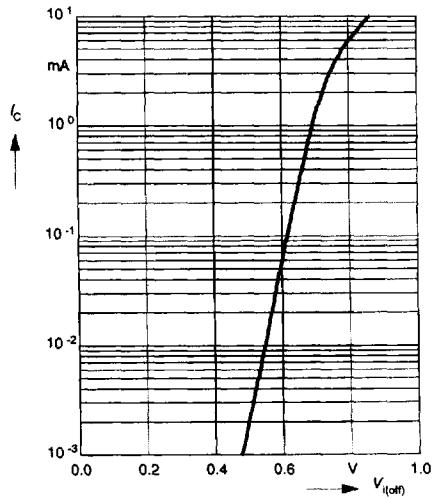
**Input on Voltage**  $V_{i(on)} = f(I_C)$   
 $V_{CE} = 0.3V$  (common emitter configuration)



**Collector-Emitter Saturation Voltage**  
 $V_{CEsat} = f(I_C)$ ,  $h_{FE} = 20$

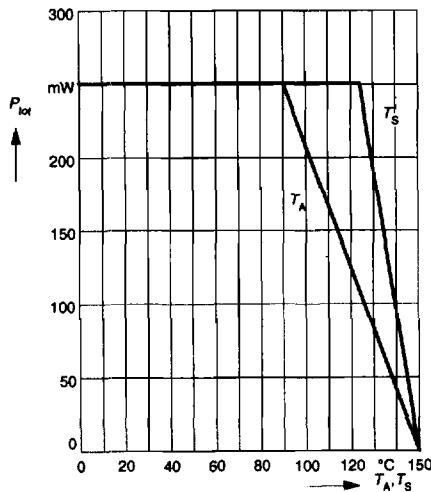


**Input off voltage**  $V_{i(off)} = f(I_C)$   
 $V_{CE} = 5V$  (common emitter configuration)



Total power dissipation  $P_{\text{tot}} = f(T_A^*; T_S)$

\* Package mounted on epoxy



Permissible Pulse Load  $R_{\text{thJS}} = f(t_p)$

Permissible Pulse Load  $P_{\text{totmax}} / P_{\text{totDC}} = f(t_p)$

